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M.2 ((P80))

4TG2-P Series

Customer:	
Customer	
Part Number:	
Innodisk	
Part	
Number:	
Innodisk	
Model Name:	
Date:	

Innodisk	Customer
Approver	Approver

Total Solution For Industrial Flash Storage

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Features:

- PCIe Gen.4 x 4, NVMe SSD
- Kioxia 3D TLC NAND
- M.2 2280-D2-M
- iPowerguard
- iDataguard
- Thermal throttling Management
- Hybrid Write
- Support AES + TCG OPAL function

Perfo	rmance:

- Sequential Read up to 6,950 MB/s
- Sequential Write up to 4,700 MB/s

Power Requirements:

Input Voltage:	3.3V±5%
Max Operating Wattage (R/W):	9.0W
Idle Wattage:	2.4W

Reliability:

Capacity	TBW (Client)	DWPD
256GB	361	1.5
512GB	768	1.6
1TB	1,828	1.9
2ТВ	4,574	2.4
4TB	8,444	2.2

Data Retention	1 Year
Warranty	3 Years

For 1 year date retention is based on NAND life end.

For warranty details, please refer to:

https://www.innodisk.com/en/support_and_service/warranty

REVISION HISTORY

Revision	Description	Date	
V1.0	First release	Apr., 2023	
V1.1	Revise Performance Noted Nov., 2023		
	Add Thermal Throttling Description		
V1.2	Update Performance Nov., 2023		
V1.3	Update TBW Apr., 2024		
	Add ESD information & 256GB information		
V1.4	Update Power Consumption Sep., 2024		
	Add 256GB Client workload		
V1.5	Update Performance Noted	Nov., 2024	

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1. Product Overview

1.1 Introduction of Innodisk M.2 (P80) 4TG2-P with AES function

Innodisk M.2 (P80) 4TG2-P is an NVM Express SSD designed as the standard M.2 form factor with PCIe interface and 3D TLC NAND Flash. M.2 (P80) 4TG2-P supports PCIe Gen. 4 x4, and it is compliant with NVMe 1.4 providing excellent performance. M.2 (P80) 4TG2-P with heat-spreading design dissipate heat generating from IC making SSD perform more steady. M.2 (P80) 4TG2-P has Die RAID protection to reduce bad blocks happening and optimize data integrity. In addition, 4TG2-P series adopt hybrid mode which enables SLC Cache up to 3% of full disk capacity followed by TLC direct write to strike balance between burst performance and steady overall stability.

Innodisk M.2 (P80) 4TG2-P provides ultra-speed and high IOPS and offers maximum capacity up to 4TB, making the SSD optimal for server and heavy data workload applications.

Innodisk M.2 (P80) 4TG2-P is designed with AES engine, which is built-in the controller. When controller receives the data package from host, AES engine encrypts the data package and save the encrypted data into NAND flash. Thus, unauthorized personal has no access to decrypt the data in NAND flash.

CAUTION TRIM must be enabled.

TRIM enables SSD's controller to skip invalid data instead of moving. It can free up significant amount of resources, extends the lifespan of SSD by reducing erase, and write cycles on the SSD. Innodisk's handling of garbage collection along with TRIM command improves write performance on SSDs.

1.2 Product View and Models

Innodisk M.2 (P80) 4TG2-P is available in follow capacities within 3D TLC flash ICs. M.2 (P80) 4TG2-P 256GB M.2 (P80) 4TG2-P 512GB M.2 (P80) 4TG2-P 1TB M.2 (P80) 4TG2-P 2TB M.2 (P80) 4TG2-P 4TB



Figure 1: Innodisk M.2 (P80) 4TG2-P (Standard)



Figure 2: Innodisk M.2 (P80) 4TG2-P (Wide-temperature)

1.3 PCIe Interface

Innodisk M.2 (P80) 4TG2-P supports PCIe Gen. 4 interface and compliant with NVMe 1.4. M.2 (P80) 4TG2-P can work under PCIe Gen. 1, Gen. 2, Gen. 3, and Gen. 4.

Most of operating system includes NVMe in-box driver now. For more information about the driver support in each OS, please visit <u>https://nvmexpress.org/drivers/</u>.



2. Product Specifications

2.1 Capacity and Device Parameters

M.2 (P80) 4TG2-P device parameters are shown in Table 1.

Table 1. Device parameters		
Capacity	LBA	User Capacity(MB)
256GB	468862128	228936
512GB	937703088	457863
1TB	1875385008	915715
2TB	3750748848	1831420
4TB	7501476528	3662830

Table 1: Device parameters

2.2 Performance

Burst Transfer Rate: 8 GB/s

Table 2: Performance - 112 Layers 3D TLC (ST)

		ST				
Capacity	Unit	256GB	512GB	1TB	2ТВ	4ТВ
Sequential**		2 750		6.050		6 100
Read (Q8T1)		2,750	5,550	6,950	6,650	6,100
Sequential**		1 100	2 200	4 100	4 700	4 450
Write (Q8T1)	MR/c	1,100	2,200	4,100	4,700	4,450
Sustained Sequential	MB/s	1 250	1 000	2.450	2 400	2 150
Read (Avg.)***		1,350	1,900	2,450	2,400	2,150
Sustained Sequential		220	450	890	1 250	1 000
Write (Avg.)***		220	450	890	1,250	1,000
4KB Random**		221 000	452,000	808.000	011 000	402.000
Read (Q32T16)	TOPC	231,000	452,000	808,000	811,000	402,000
4KB Random**	IOPS	204 000	E70.000	600.000	711 000	701 000
Write (Q32T16)		294,000	570,000	690,000	711,000	701,000

		WТ				
Capacity	Unit	256GB	512GB	1TB	2ТВ	4TB
Sequential**		2 000	E 900	6 050	6 550	6 500
Read (Q8T1)		2,900	5,800	6,950	6,550	6,500
Sequential**		1 150	2 250	4 100	4 700	4 500
Write (Q8T1)	MR/c	1,150	2,250	4,100	4,700	4,500
Sustained Sequential	MB/s	1 500			2 450	2 1 5 0
Read (Avg.)***		1,500	2,050	2,550	2,450	2,150
Sustained Sequential		450	450	870	1 500	1 200
Write (Avg.)***		450	450	870	1,500	1,200
4KB Random**		251 000	404 000	916 000	820.000	001 000
Read (Q32T16)	TOPE	251,000	494,000	816,000	820,000	901,000
4KB Random**	IOPS	205 000	502.000	607.000	714 000	774 000
Write (Q32T16)		295,000	592,000	697,000	714,000	774,000

Table 3: Performance - 112 Layers 3D TLC (WT)

Note: * Performance results are measured in Room Temperature with Out-of-Box devices and may vary depending on overall system setup. In addition, 4TG2-P series adopt hybrid mode which enables SLC Cache up to 3% of full disk capacity followed by TLC direct write to strike balance between burst performance and steady overall stability.

** Performance results are based on CrystalDiskMark 8.0.1 with file size 1000MB. Unit of 4KB items is I.O.P.S.

*** Performance results are based on AIDA 64 v5.98 with block size 1MB of Linear Read & Write Test Performance may be different because ST and WT adopt different thermal solutions.

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 4: Innodisk M.2 (P80) 4TG2-P Power Requirement

Item	Symbol	Rating	Unit
Input voltage	VIN	+3.3 DC +- 5%	V

2.3.2 Power Consumption

Tuble 51 Typical Tower consumption		
Mode	Power Consumption (W)	
Read	9.1	
Write	9.0	
Idle	2.2	
Power-on peak	9.9	

Table 5: Typical Power Consumption

Target: 4TB M.2 (P80) 4TG2-P

Note: Current results may vary depending on system components and power circuit design

Please refer to the test report for other capacities

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 6: Temperature range for M.2 (P80) 4TG2-P

Temperature	Range
Operating	Standard Grade: 0°C to +70°C Industrial Grade: -40°C to +85°C
Storage	-40°C to +85°C SOP

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 7: Shock/Vibration Testing for M.2 (P80) 4TG2-P

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various M.2 (P80) 4TG2-P configurations. The analysis was performed using a RAM Commander[™] failure rate prediction.

- **Failure Rate**: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF)**: A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 8: M.2 (P80) 4TG2-P MTBF

Product	Condition	MTBF (Hours)
Innodisk M.2 (P80) 4TG2-P	Telcordia SR-332 GB, 25°C	>3,000,000

2.5 CE and FCC Compatibility

M.2 (P80) 4TG2-P conforms to CE and FCC requirements.

Table 9: M.2 (P80)	4TG2-P ESD
--------------------	------------

Reliability	Reference standards
Electrostatic Discharge (ESD)	IEC 61000-4-2 ESD

2.6 RoHS Compliance

M.2 (P80) 4TG2-P is fully compliant with RoHS directive.



2.7 Reliability

Table 10: M.2 (P80) 4TG2-P TBW

Parameter	Value		
Flash endurance	3,000 P/E cycles		
Error Correct Code	Support(LDPC)		
Data Retention	Under 40°C:		
	1 Years at NAND Life End		
TBW* (Total Bytes Written) Unit: TB			
Capacity	Sequential workload	Client workload	
256GB	681	361	
512GB	1363	768	
1TB	2,727	1,828	
2TB	5,454	4,574	
4TB	10,909	8,444	

* Note:

1. Sequential: Mainly sequential write are estimated by PassMark Burnin Test v8.1 pro.

2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)

3. Based on out-of-box performance.

4. Current TBW Values are for reference only. Actual figures will be released after MP.

2.8 Transfer Mode

M.2 (P80) 4TG2-P support following transfer mode:

PCIe Gen. 4: 8GB/s

PCIe Gen. 3: 4GB/s

PCIe Gen. 2: 2GB/s

PCIe Gen. 1: 1GB/s

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2.9 Pin Assignment

Innodisk M.2 (P80) 4TG2-P follows standard M.2 spec, socket 3, key M PCIe-based SSD pinout. See Table 11 for M.2 (P80) 4TG2-P pin assignment.

Signal Name	Pin #	Pin #	Signal Name
		75	GND
3.3V	74	73	GND
3.3V	72	71	GND
3.3V	70	69	NC
NC	68	67	NC
Notch	66	65	Notch
Notch	64	63	Notch
Notch	62	61	Notch
Notch	60	59	Notch
NC	58		
NC	56	57	GND
NC	54	55	REFCLKp
CLKREQ# (I/O)(0/3.3V)	52	53	REFCLKn
PERST# (I)(0/3.3V)	50	51	GND
NC	48	49	PERp0
NC	46	47	PERn0
ALERT	44	45	GND
NC(reserved for	42	43	PETp0
SMB_DATA)(I/O)(O/1.8V)			
NC(reserved for SMB_CLK)	40	41	PETn0
NC	38	39	GND
NC	36	37	PERp1
NC	34	35	PERn1
NC	32	33	GND
NC	30	31	PETp1
NC	28	29	PETn1
NC	26	27	GND
NC	24	25	PERp2
NC	22	23	PERn2
NC	20	21	GND
3.3V	18	19	PETp2
3.3V	16	17	PETn2
3.3V	14	15	GND
3.3V	12	13	PERp3
NC	10	11	PERn3
NC	8	9	GND
NC	6	7	РЕТр3
3.3V	4	5	PETn3
3.3V	2	3	GND
		1	GND

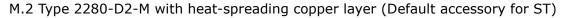
Table 11: Innodisk M.2 (P80) 4TG2-P Pin Assignment



Table 12: Innodisk M.2 (P80) 4TG2-P LED indicator

LED Color	Function	
Creen	Power on	
Green	Access	

2.10 Mechanical Dimensions



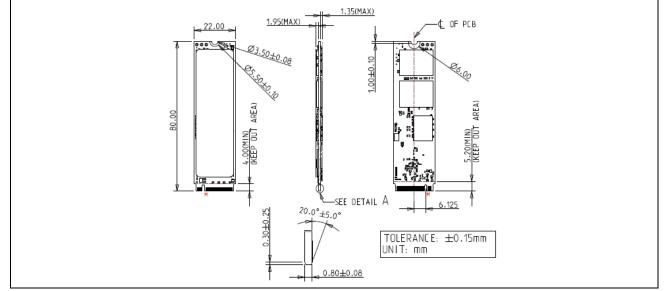


Figure 3: Innodisk M.2 (P80) 4TG2-P with heat-spreading copper layer diagram

M.2 Type 2280-D2-M with heatsink (Default accessory for WT)

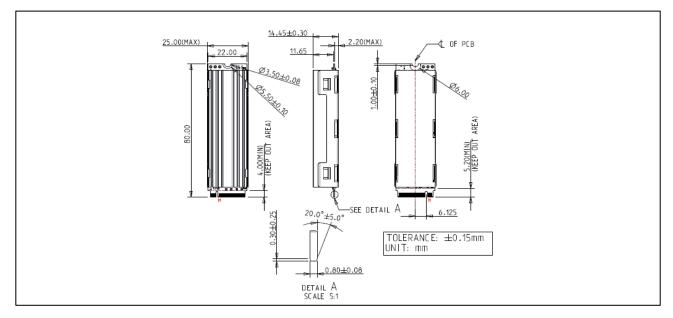


Figure 4: Innodisk M.2 (P80) 4TG2-P with heatsink diagram

Note: The appearance of silicone oil seeping out from the inside of the thermal pad is a normal occurrence.

Silicone oil is not electrically conductive, so it does not impact the functionality of SSD.



M.2 Type 2280-D2-M

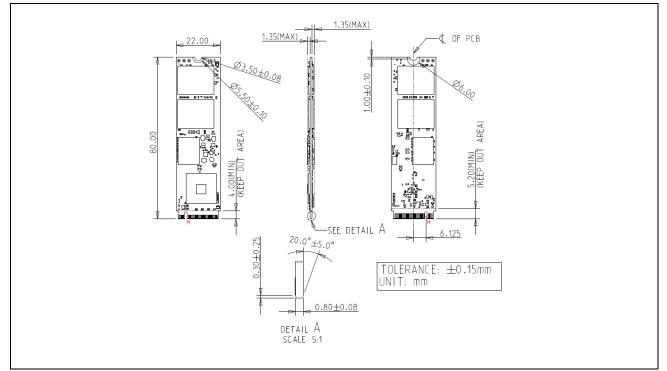


Figure 5: Innodisk M.2 (P80) 4TG2-P

2.11 Assembly Weight

An Innodisk M.2 (P80) 4TG2-P within NAND flash ICs, 512GB's weight is 7 grams approximately.

2.12 Seek Time

Innodisk M.2 (P80) 4TG2-P is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 NAND Flash Memory

Innodisk M.2 (P80) 4TG2-P uses 3D TLC NAND flash memory, which is non-volatility, high reliability and high speed memory storage.



3. Theory of Operation

3.1 Overview

Figure 6 shows the operation of Innodisk M.2 (P80) 4TG2-P from the system level, including the major hardware blocks.

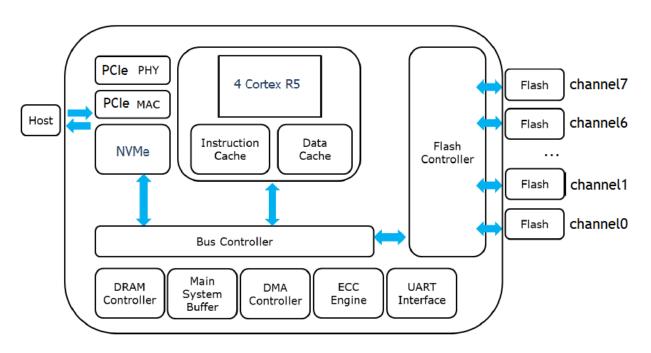


Figure 6: Innodisk M.2 (P80) 4TG2-P Block Diagram

Innodisk M.2 (P80) 4TG2-P integrates a PCIe Gen 4x4 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard NVM protocol. Communication with the flash device(s) occurs through the flash interface. The AES engine was built-in the DP2 controller. When M.2 (P80) 4TG2-P is initiated with Firmware, AES engine will generate a random number to be an AES key. Each SSD has a unique AES key when it leaves the factory.

3.2 PCIe Gen. 4 x4 Controller

Innodisk M.2 (P80) 4TG2-P is a PCIe Gen. 4x4 controller is compliant with NVMe 1.4, up to 32.0Gbps transfer speed. Also it is compliant with PCIe Gen. 1, Gen. 2, Gen. 3 and Gen. 4 specification. The controller supports up to 8 channels for flash interface.

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3.3 Error Detection and Correction

Innodisk M.2 (P80) 4TG2-P is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk M.2 (P80) 4TG2-P uses a combination of two types of wear leveling- dynamic and static wear leveling- to distribute write cycling across an SSD and balance erase count of each block, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 iData Guard

Innodisk's iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to the SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

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3.8 Thermal Management

M.2 (P80) 4TG2-P has built-in thermal sensor which can detect environment temperature of SSD. In the meantime, firmware will monitor the thermal sensor to prevent any failure of overheating. During extreme temperature, firmware will adjust the data transfer behavior to maintain the SSD's reliable operation.

3.9 Thermal Throttling

Thermal throttling is a protective mechanism designed to safeguard components from potential damage caused by excessive temperatures. When an SSD approaches a critical temperature threshold, Innodisk firmware activates the thermal throttling mechanism to regulate the SSD's temperature. Thermal throttling is crucial for SSDs since it prevents drive damage, which could otherwise result in data loss. However, it's worth noting that when thermal throttling is activated, read and write tasks may experience a reduction in speed.

3.10 iPower Guard

iPower Guard technology is a set of preventive measures that protect the SSD in an unstable power supply environment. This comprehensive package comprises safeguards for startup and shutdown to maintain device performance and ensure data integrity.

3.11 Die RAID

Die RAID is a controller function which leveraged user capacity to back up the data in NAND flash. Die RAID supported can ensure the user data in the NAND Flash more consistent in certain scenario. Innodisk M.2 (P80) 4TG2-P series is default enable the Die RAID function for the industrial application.

3.12 SLC Cache

4TG2-P series adopt hybrid mode which enables SLC Cache up to 3% of full disk capacity followed by TLC direct write to strike balance between burst performance and steady overall stability. The SLC Cache buffer size are defined as table below.

Capacity	512GB	1TB	2TB	4TB									
SLC cache (GB)	15.36	30.72	61.44	81.92									
SLC cache (%)	3	3	3	2									

Table 13: M.2 (P80) 4TG2-P SLC cache



3.13 TCG OPAL

OPAL is a set of specifications for features of data storage devices that enhance security. These specifications are published by the Trusted Computing Group's Storage Work Group. Innodisk 4TG2-P is compliant with TCG OPAL 2.0(*1). The capability of TCG OPAL Security mode allows multiple users with independent access control to read/write/erase independent data areas (LBA ranges). Each locking range adjusts by authenticated authority. Note that by default there is a single "Global Range" that encompasses the whole user data area. In TCG Opal Security Mode, Revert, Revert SP and GenKey command can erase all of data including global range and locking range; in the meantime generate the new encrypted key.

*1. You need to install TCG OPAL software to implement OPAL function, which is supplied by TCG OPAL software developed company



4. Installation Requirements

4.1 M.2 (P80) 4TG2-P Pin Directions

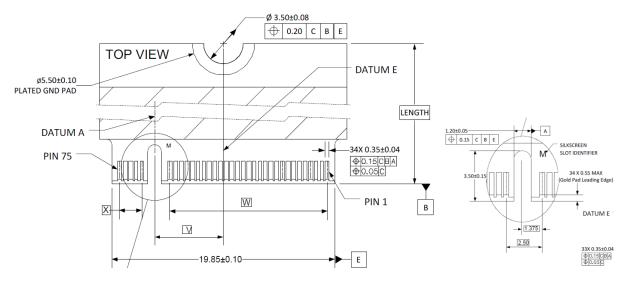


Figure 7: Signal Segment and Power Segment

4.2 Electrical Connections for M.2 (P80) 4TG2-P

M.2 interconnect is based on a 75 position Edge Card connector. The 75 position connector is intended to be keyed so as to distinguish between families of host interfaces and the various Sockets used in general Platforms. M.2 (P80) 4TG2-P is compliant with M.2 Socket 3 key M. M.2 (P80) 4TG2-P is compatible with host connector H4.2.

4.3 Device Drive

M.2 (P80) 4TG2-P is compliant with NVMe 1.4. Both Operation System and BIOS should include NVMe driver to compatible with NVMe device. Nowadays, most of OS includes NVMe in-box driver now. For more information about the driver support in each OS, please visit the website <u>https://nvmexpress.org/drivers/</u>. For BIOS NVMe driver support please contact with motherboard manufacture.



5. SMART / Health Information

This log page is used to provide SMART and general health information. The information provided is over the life of the controller and is retained across power cycles. More details about Set Features command; please refer to NVM Express 1.3

5.1 Get Log Page (Log Identifier 02h)

Innodisk 4TG2-P series SMART / Health Information Log are listed in following table.

Bytes	Description	Description										
0	Critical Warning: This field indicates critical warnings for the state of the control											
	corresponds	corresponds to a critical warning type; multiple bits may be set. If a bit is cleared to '0', then that										
	critical warni	critical warning does not apply. Critical warnings may result in an asynchronous event notification to										
	the host. Bits	the host. Bits in this field represent the current associated state and are not persistent.										
	Bit	Definition										
	00	If set to `1', then the available spare space has fallen below the threshold.										
	01	If set to `1', then a temperature is above an over temperature threshold or										
	01	below an under temperature threshold.										
		If set to `1', then the NVM subsystem reliability has been degraded due to										
	02	significant media related errors or any internal error that degrades NVM										
		subsystem reliability.										
	03	03 If set to `1', then the media has been placed in read only mode.										
	04	If set to '1', then the volatile memory backup device has failed. This field is										
		only valid if the controller has a volatile memory backup solution.										
	07:05	Reserved										
2:1	Composite ⁻	Composite Temperature: Contains a value corresponding to a temperature in degrees Kelvin that										
	represents th	represents the current composite temperature of the controller and namespace(s) associated with that										
	controller. Th	controller. The manner in which this value is computed is implementation specific and may not represent										
	the actual ter	the actual temperature of any physical point in the NVM subsystem. The value of this field may be used										
	to trigger an	to trigger an asynchronous event.										
	Warning and	Warning and critical overheating composite temperature threshold values are reported by the WCTEMP										
	and CCTEMP	and CCTEMP fields in the Identify Controller data structure.										
3	Available S	pare: Contains a normalized percentage (0 to 100%) of the remaining spare cap	acity									
	available.	available.										
4	Available Sp	Available Spare Threshold: When the Available Spare falls below the threshold indicated in this field,										
	an asynchror	an asynchronous event completion may occur. The value is indicated as a normalized percentage (0 to										

Table 14: Get Log Page – SMART / Health Information Log

	100%).									
5	Percentage Used: Contains a vendor specific estimate of the percentage of NVM subsystem life used									
	based on the actual usage and the manufacturer's prediction of NVM life. A value of 100 indicates that									
	the estimated endurance of the NVM in the NVM subsystem has been consumed, but may not indicate									
	an NVM subsystem failure. The value is allowed to exceed 100. Percentages greater than 254 shall be									
	represented as 255. This value shall be updated once per power-on hour (when the controller is not in									
	a sleep state).									
	Refer to the JEDEC JESD218A standard for SSD device life and endurance measurement techniques.									
31:6	Reserved									
47:32	Data Units Read: Contains the number of 512 byte data units the host has read from the controller;									
	this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds									
	to 1000 units of 512 bytes read) and is rounded up. When the LBA size is a value other than 512 bytes,									
	the controller shall convert the amount of data read to 512 byte units.									
	For the NVM command set, logical blocks read as part of Compare and Read operations shall be included									
	in this value.									
63:48	Data Units Written: Contains the number of 512 byte data units the host has written to the controller;									
	this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds									
	to 1000 units of 512 bytes written) and is rounded up. When the LBA size is a value other than 512									
	bytes, the controller shall convert the amount of data written to 512 byte units.									
	For the NVM command set, logical blocks written as part of Write operations shall be included in this									
	value. Write Uncorrectable commands shall not impact this value.									
79:64	Host Read Commands: Contains the number of read commands completed by the controller.									
	For the NVM command set, this is the number of Compare and Read commands.									
95:80	Host Write Commands: Contains the number of write commands completed by the controller.									
	For the NVM command set, this is the number of Write commands.									
111:96	Controller Busy Time: Contains the amount of time the controller is busy with I/O commands. The									
	controller is busy when there is a command outstanding to an I/O Queue (specifically, a command was									
	issued via an I/O Submission Queue Tail doorbell write and the corresponding completion queue entry									
	has not been posted yet to the associated I/O Completion Queue). This value is reported in minutes.									
127:112	Power Cycles: Contains the number of power cycles.									
143:128	Power On Hours: Contains the number of power-on hours. This may not include time that the									
	controller was powered and in a non-operational power state.									
159:144	Unsafe Shutdowns: Contains the number of unsafe shutdowns. This count is incremented when a									
	shutdown notification (CC.SHN) is not received prior to loss of power.									
175:160	Media and Data Integrity Errors: Contains the number of occurrences where the controller detected									
	an unrecovered data integrity error. Errors such as uncorrectable ECC, CRC checksum failure, or LBA									
	tag mismatch are included in this field.									
191:176	Number of Error Information Log Entries: Contains the number of Error Information log entries									
	over the life of the controller.									
195:192	Warning Composite Temperature Time: Contains the amount of time in minutes that the controller									

innodisk	M.2 (P80) 4TG2-P
	is operational and the Composite Temperature is greater than or equal to the Warning Composite
	Temperature Threshold (WCTEMP) field and less than the Critical Composite Temperature Threshold
	(CCTEMP) field in the Identify Controller data structure.
	If the value of the WCTEMP or CCTEMP field is 0h, then this field is always cleared to 0h regardless of
	the Composite Temperature value.
199:196	Critical Composite Temperature Time: Contains the amount of time in minutes that the controller
	is operational and the Composite Temperature is greater than the Critical Composite Temperature
	Threshold (CCTEMP) field in the Identify Controller data structure.
	If the value of the CCTEMP field is 0h, then this field is always cleared to 0h regardless of the Composite
	Temperature value.
201:200	Temperature Sensor 1: Controller's Tj temperature
203:202	Temperature Sensor 2: Flash package's Tj temperature (Channel #0 CE #0). This Flash package is
	located the closet to the controller IC on M.2 family.
205:204	Temperature Sensor 3: Flash package's Tj temperature (Channel #0 CE #0).
	This Flash package is located the closet to the controller IC on M.2 family.
207:206	Temperature Sensor 4: Flash package's Tj temperature (Channel #7 CE #0).
209:208	Temperature Sensor 5: Flash Tj max temperature from Channel #0 to Channel #3 Flash packages.
211:210	Temperature Sensor 6: Flash Tj max temperature from Channel #4 to Channel #7 Flash packages.
213:212	Temperature Sensor 7: Flash Tj minimum temperature from Channel #0 to Channel #3 Flash
	packages.
215:214	Temperature Sensor 8: Flash Tj minimum temperature from Channel #4 to Channel #7 Flash
	packages.
219:216	Thermal Management Temperature 1 Transition Count: Contains the number of times the
	controller transitioned to lower power active power states or performed vendor specific thermal
	management actions while minimizing the impact on performance in order to attempt to reduce the
	Composite Temperature because of the host controlled thermal management feature (refer to section
	8.4.5) (i.e., the Composite Temperature rose above the Thermal Management Temperature 1.) This
	counter shall not wrap once it reaches its maximum value. A value of zero, indicates that this transition
	has never occurred or this field is not implemented.
223:220	Thermal Management Temperature 2 Transition Count: Contains the number of times the
	controller transitioned to lower power active power states or performed vendor specific thermal
	management actions regardless of the impact on performance (e.g., heavy throttling) in order to
	attempt to reduce the Composite Temperature because of the host controlled thermal management
	feature (refer to section 8.4.5) (i.e., the Composite Temperature rose above the Thermal Management
	Temperature 2.) This counter shall not wrap once it reaches its maximum value. A value of zero,
	indicates that this transition has never occurred or this field is not implemented.
227:224	Total Time For Thermal Management Temperature 1: Contains the number of seconds that the
	controller had transitioned to lower power active power states or performed vendor specific thermal
	management actions while minimizing the impact on performance in order to attempt to reduce the
	Composite Temperature because of the host controlled thermal management feature (refer to section

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	8.4.5). This counter shall not wrap once it reaches its maximum value. A value of zero, indicates that
	this transition has never occurred or this field is not implemented.
231:228	Total Time For Thermal Management Temperature 2: Contains the number of seconds that the
	controller had transitioned to lower power active power states or performed vendor specific thermal
	management actions regardless of the impact on performance (e.g., heavy throttling) in order to
	attempt to reduce the Composite Temperature because of the host controlled thermal management
	feature (refer to section 8.4.5). This counter shall not wrap once it reaches its maximum value. A value
	of zero, indicates that this transition has never occurred or this field is not implemented.
511:232	Reserved

The innodisk M.2 (P80) series thermal sensor take ambient air temperature as a reference with any airflow condition, and the data can refer to iSMART.

Notes: More detailed health info has been defined by innodisk and will be shown on iSMART V5.3.21 (or later version).

6. Part Number Rule

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21
CODE	D	G	М	2	8	I	С	1	2	D	Р	2	к	w	С	E	F	(H)	-	x	x
									D	efini	tion										
Code 1 st (Disk)									Code 14 th (Operation Temperature)												
D : Disk								C	C: St	anda	rd G	rade	(0 °C	~ +	70 ℃)					
Code 2 nd (Feature set)								١	N: In	dust	rial (Grad	e (-4	• 0 °C ^	- +8	5℃)					
G : EverGreen Series																					
	С	ode	3 rd /	~5 th	(Fo	rm fa	acto	r)			Code 15 th (Internal control)										
M28: M	1.2 T	ype	2280)-D2	-M					A	A~Z: BGA PCB version.										
		Cod	e 7 ^{ti}	^h ~9	th (C	apa	city)				Code 16 th (Channel of data transfer)										
B56:25	6GB		C12	2:51	2GB		01T:	1TB		C	Q: Four Channels										
02T:2T	В		047	T:4TE	3					E	E: Eight Channels										
	C	ode	10 th	~12	2 th (0	Cont	rolle	er)			Code 17 th (Flash Type)										
DP2: P	CIe 4	4TG2	2-P w	ith A	AES+	TCG	OPA	L fui	nctio	n F	F: Kioxia 3D TLC										
	Code 13 th (Flash mode)								Code 18 th (Optional function)												
K: 3D ⁻	K: 3D TLC 112 layers							ŀ	H: wi	th he	eatsi	nk a	ccess	sory	(for	WT)					
									Code 20 th ~ (Customize code)												